5. (Amended) A liquid crystal display device comprising:

a pixel electrode at a pixel area between a gate line and a data line;

a charging device on the gate line, the charging device comprising:

a metal thin film;

a light-shielding member overlapping the charging device and extending from an end at the pixel electrode side of the metal thin film into the pixel area with a margin sufficient to block light incident on the metal thin film.

9. (Amended) A liquid crystal display device comprising:

a pixel electrode at a pixel area between a gate line and a data line;

a thin film transistor at an intersection between the gate line and the data line and including a first metal thin film;

a storage capacitor on the gate line and including a second metal thin film;

a black matrix at a boundary portion between pixel areas;

a first dummy black matrix connected to the black matrix and extending from an end at the pixel electrode side of the first metal thin film into the pixel area with a margin sufficient to block light incident on the first metal thin film; and

a second dummy black matrix connected to the black matrix and extending from an end at the pixel electrode side of the second metal thin film into the pixel area with a margin sufficient to block light incident on the second metal thin film.

11. (Amended) A method of fabricating a liquid crystal display device comprising the steps of:

forming a pixel electrode at a pixel area between a gate line and a data line;

forming a switching device including a metal thin film at an intersection between the gate line and the data line; and

forming a light-shielding member for blocking light incident on the metal thin film to overlap with the switching device, the light-shielding member extending from an end at the pixel electrode side of a metal thin film of the switching device into the pixel area with a margin sufficient to block the light incident on the metal thin film.

15. (Amended) A method of fabricating a liquid crystal display device comprising the steps of:

forming a pixel electrode at a pixel area between a gate line and a data line;

forming a charging device including a first metal thin film on the gate line; and

forming a light-shielding member for blocking light incident on the metal thin film to overlap the metal thin film, the light-shielding member extending from an end at the pixel electrode side of the first metal thin film into the pixel area with a margin sufficient to block the light incident on the metal thin film.

19. (Amended) A method of fabricating a liquid crystal display device comprising the steps of:

forming a pixel electrode at a pixel area between a gate line and a data line on a rear substrate;

forming a thin film transistor including a first metal thin film at an intersection between the gate line and the data line on the rear substrate;

forming a storage capacitor including a second metal thin film on the rear substrate and overlapping the gate line;

forming a black matrix on a front substrate opposed to the rear substrate at a boundary portion between pixel areas;

forming a first dummy black matrix extending from an end at the pixel electrode side of the first metal thin film into the pixel area on the front substrate with a margin sufficient to block light incident on the first metal thin film; and

forming a second dummy black matrix extending from an end at the pixel electrode side of the second metal thin film into the pixel area on the front substrate with a margin sufficient to block light incident on the second thin film.